XUV nanosecond laser ablation for pulsed laser deposition of lithium fluoride and caesium iodide

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In this work we demonstrate results of interaction of nanosecond XUV laser pulses at wavelength of 46.9 nm with lithium fluoride (LiF), caesium iodide (CsI) and golden (Au) samples. All of these materials were used for pulsed laser deposition (PLD) on magnesium oxide (MgO) substrate. Samples were irradiated by series with a different number of laser shots at various fluency values. Deposited layers were analysed by optical microscope, atomic force microscope (AFM), X-ray fluorescence (XRF) and finally by X-ray powder diffraction (XRD).

Introduction

Laser ablation of solid surfaces is important in a numerous of applications such as advanced micromachining, surgery, X-ray laser generation, PLD, mass spectrometry of biomolecules, art cleaning/restoration and fundamental physics studies. Conventional long wavelength laser very often used for PLD of CsI as a typical ionic crystal [1]. Deposited thin films of CsI could be used as a traditional scintillation detector [2] and relatively stable photocathodes [3]. Production of LiF by PLD technics is very interesting for a variety of reasons. Thin LiF coatings of electrodes could reduce the work function of metal [4] and could improve the performance of organic electroluminescence devices [5]. Recently, some ablation experiments with CsI [6] and LiF [7] by XUV laser (with wavelength of 46.9 nm) has been performed. In this paper we present not only results of ablation of CsI, LiF and Au surfaces, but also analysis of deposited materials on MgO substrate. Samples were irradiated by 2, 5, 10, 20, 40 and 80 laser pulses in the range of energies from 110 to 130 µJ (all energies were estimated in a primary beam).
Apparatus

The arrangement of the XUV laser-matter interaction experiments is illustrated in Fig. 1. As a source of intense XUV radiation was used Ne-like Ar capillary discharge laser with wavelength of 46.9 nm. Our driver CAPEX consists of a Marx generator, coupling section, a coaxial line filled with deionized water, self-breakdown spark gap and a ceramic capillary. For ablation and PLD purposes apparatus was extended for vacuum chamber with vacuum photodiode, Sc/Si multilayer mirror (with reflectivity of about 13%) and interaction tube with samples. In more details apparatus CAPEX was described in the early published papers [8]-[10]. Estimation of laser energy was performed from measurements of intensity of XUV radiation with Al filters of different thickness by vacuum photodiode [11]-[12].

Fig. 1 Experimental apparatus CAPEX with extension for ablation experiments.

Results

The LiF, CsI and layer of Au on PMMA (thickness of 50 nm) were deposited on MgO substrate by PLD technics. Substrates were placed at distance about 1 mm from samples and angles between focused laser beam and sample were 30° for Au, 48° for LiF and 40° for CsI. At the first, deposited thin films on MgO substrate were observed by optical microscope (see Fig. 2): Au and CsI deposited layers were clearly visible, but in the case of

Fig. 2 Deposited films on MgO substrate observed by optical microscope: left – layer of CsI after 80, 40 and 20 laser pulses (from left to right), right – layer of Au after 10 laser pulses.
The LiF situation was quite complicated due to transparency of deposited material and substrate. In the next step, ablation craters on the surface of the LiF and CsI samples were analyzed by AFM and optical surface profiler Zygo based on the white light interferometry. In the case of Au (when the substrate stayed on the same place and the sample was moved), all material was ablated by 10 laser pulses with average energy of 110 μJ/pulse in 10 positions (thickness in each position is about 50 nm) on the sample. Etch rate of LiF sample is decreasing with more pulses up to 9 nm/pulse (for 80 laser shots with average energy of 119 μJ/pulse). And similar situation was observed on CsI sample when etch rate is decreasing to 17 nm/pulse (for 80 laser shots with average energy of 113 μJ/pulse). And finally, deposited film of CsI on the MgO substrate was characterized by XRD and XRF conducted with a Rigaku NEX CG spectrometer (Fig. 3). Emission lines on the spectrum with energies of 4.272 keV, 4.286 keV, 4.652 keV, 4.975 keV and 4.989 keV correspond to Lα₂, Lβ₁, Lβ₄, Lβ₁₀ and Lβ₇ transitions of Cs. XRD pattern of deposited CsI thin films prepared by PLD technique is shown in right part of the Fig. 3. The XRD scan exhibits a number of intense and sharp peaks which are assigned to the indicated Bragg reflections from CsI crystal. Deposited CsI layer was presented as a compound at the surface, which was indicated by peaks in the 2θ spectra. Measured peaks at angles 27.7, 48.7 and 64.4 correspond to the lattice plane (110), (211) and (310) for CsI crystal. When we compare obtained data with data at [13] where XRD patterns were obtained for different thickness of CsI layer, we could estimate thickness of deposited layer of CsI on MgO substrate by PLD technics in range from 20 to 100 nm.

Conclusions

In this paper we investigated potential use of XUV ablation of Au, LiF and CsI (which is difficult to ablate by UV-Vis-NIR lasers) for PLD purpose. It turned out that deposited layers of Au and CsI
are clearly visible by optical microscope. Analysis of the deposited layer using XRF and XRD shows that PLD of CsI as a compound was successful. Other materials will be analysed in a near future.

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**References**